NSN 5961-01-342-5821

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-342-5821 **Inclosure Material:** Metal **Overall Length:** 1.550 inches **Overall Height:** Between 0.250 inches and 0.300 inches Overall Width: 1.050 inches **Mounting Facility Quantity:** 2 **Internal Configuration:** Junction contact-darlington connected Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1000.0 collector-to-emitter, with voltage between base and emitter and 750.0 collector-to-emitter, substaining voltage, base open-circuited and 8.0 emitter to base voltage, dc **Current Rating Per Characteristic:** 20.00 amperes source cutoff current and 10.00 amperes source cutoff current **Power Rating Per Characteristic:** 250.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:**

Fiig: A110a0

No